Progress in solid electrochemical gas sensors based on NASICON and oxide electrodes

Xishuang Liang ¹, Biao Wang ², Houbo Zhang ¹, Quan Diao ¹, Baofu Quan ¹ and Geyu Lu ^{1*}

1 State Key Laboratory on Integrated Optoelectronics, College of Electronic Science and Engineering, Jilin University, 2699 Qianjin Street, Changchun 130012, China;

Corresponding e-mail address: lugy@jlu.edu.cn

2 Changchun Institute of Optics, Fine Mechanics and Physics, CAS, 3888 Dong Nanhu Road, Changchun 130033, China.

Abstract

The mixed-potential type NASICON-based sensor attached with an oxide electrode is generally used at intermediate temperatures and more suitable for monitoring the harmful and toxic gases in the atmospheric environment. This presentation focuses on the exploration of new oxide electrode materials and the design of new sensor structure for increasing the sensing performance of the sensor based on NASICON and oxide electrode.

Key words: NASICON, gas sensor, oxide electrode, mixed potential

1. Introduction

With the increasing of world's population and the acceleration of the industrialization process. lots of harmful gases (CO₂, SO_x, NO_x, H₂S, NH₃, CO and so on) from the power generation, heat supplying, metallurgy, chemical production and motor vehicle lead to the greenhouse effect, acid rain, photochemical smog and other environmental disasters. Therefore, the highperformance environment gas sensors have been urgently desired for detecting and monitoring these hazardous gases. Up to now, various kinds of gas sensors based on semiconductor oxides [1], organic thin films [2] and solid electrolytes [3] have been developed. Among them, the solid electrolyte type sensors exhibit excellent sensing performances, such as sensitivity, rapid response kinetics, outstanding selectivity and reproducibility. For the solid electrolyte sensors, most researches focused on the sensors based on yttria stablized zirconia (YSZ) and sodium super ionic conductor (NASICON). In general, the YSZbased sensor was operated at high temperature (600-800°C), so it seems to be inappropriate for detecting the gases in atmospheric environment because of its low sensitivity as well as high power consumption. Contrary to the YSZ-based sensors, the mixed potential type sensors based on NASICON are generally operated at the intermediate temperatures (300-500°C), so they are more suitable for detecting the atmospheric hazardous gases in the the environment. According to sensing

mechanism, the NASICON-based gas sensors are mainly divided into three types: the currenttype, the equilibrium-potential-type and mixedpotential-type. N. Miura et al. developed the current NO2 sensor based on NASICON and NaNO₂ electrode. The sensor has good linearity within the range of 10ppb-1ppm concentration at 150°C [4]. As for the equilibrium potential type sensors, N. Yamazoe et al systematically researched the CO2 sensors using a series of composite carbonate, e.g. CO₂ sensors with good moisture resistance have been fabricated by using Na₂CO₃-BaCO₃ and Li₂CO₃-BaCO₃ as the auxiliary electrode [5, 6]. S. Choi et al. reported SO₂ sensor using Na₂SO₄ and Na₂SO₄-BaSO₄ as auxiliary electrodes [7], which showed excellent stability. K. Obata et al. developed the equilibrium-potential-type NO₂ sensor with ITO and NaNO2-Li2CO3 as the auxiliary electrode, which had low detecting limit (about 2ppm) and an excellent moisture resistance [8]. For above two types of sensors, the long-time stability and moisture resistance need further be improved, due to the hygroscopicity of the oxysalt auxiliary electrode as well as the interface reaction between the oxysalt and NASICON. Unlike these two types of sensors, the mixed-potential-type sensor based on NASICON uses an oxide as a sensing electrode which has good moisture resistance and not directly involved in the electrode reaction (electrode catalyst), so it has been a hot research topic in recent years. Y. Shimizu et al developed a CO₂ sensor with $NdCoO_3$ and $La_{0.8}Ba_{0.2}CoO_3$ as sensing electrode, which improved the stability and moisture resistance, but the sensitivity need to be improved [9]. They also developed mixed-potential-type NO_x sensor with $Pb_2Ru_{1.9}V_{0.1}O_{7-z}$ as sensing electrode. However, the systematic investigation about the NASICON-based mixed potential type sensor has been scarcely reported.

This paper provides an overview and mainly discusses the mixed-potential-type gas sensors based on NASICON solid electrolyte and metal oxide electrodes developed by our group.

2. Methods

The NASICON was synthesized with ZrO(NO₃)₂, NaNO₃, (NH₄)₂HPO₄ and Si(C₂H₅O)₄ by sol-gel process. The sensor was fabricated with an alumina tube of 6 mm long, 0.8 and 1.2 mm in inner and outer diameters. The NASICON precursor was applied on an alumina tube twice and sintered at 900°C for 6 h in air. Then noble metal (Pt or Au) and oxide layers were formed on the two ends of NASICON layer.

3. Results and Discussion

Table 1 shows some results of the NASICON based gas sensors using oxide electrodes. As shown in the table 1. For improving the performance of sensors, two main approaches have been utilized.

First, some novel oxide electrode materials for sensing H_2S , Cl_2 , SO_2 , NH_3 have been developed. For example, we have reported the NASICON based H_2S sensor using Pr_6O_{11} -doped SnO_2 electrode as sensing electrode. It showed excellent sensing properties to H_2S at intermediate temperatures. The EMF value of the sensor was almost proportional to the logarithm of H_2S concentration, and the sensitivity(slope) was 74 mV/decade at 300°C [10], as shown in Fig. 1.

The sensor using CaMg₃(SiO₃)₄-doped CdS sintered at 600 °C exhibited excellent sensing properties to 1–10 ppm chlorine in air at 100–250 °C [11]. Its sensitivity (slope) was 392 mV/decade at 200°C. It also showed a good selectivity to Cl_2 against H_2S , SO_2 , NO_2 , NH_3 , CH_4 and CO, as shown in Fig. 2.

A high performance SO_2 sensor was developed by combining NASICON with V_2O_5 -doped TiO_2 sensing electrode [12]. The sensor displayed excellent response and recovery characteristics to 1 – 50ppm SO_2 at 300 °C, as shown in Fig. 3. For increasing the sensitivity of the sensor to NH₃, a porous Cr_2O_3 prepared by doping C was utilized as the sensing electrode [13]. As shown in Fig. 4, the sensor using porous Cr_2O_3 showed much higher sensitivity than that using

 Cr_2O_3 particle. It can be attributted to the speedy diffusion through the porous sensing layer and lower loss of the NH₃ concentration in the sensing layer.

Second, in order to improve the sensing performance and realize simple sensor array, we also focused on designing new device structures, such as the dual-function sensor using double oxide electrodes and the buried structure device for blocking the electrochemical reactions on the reference

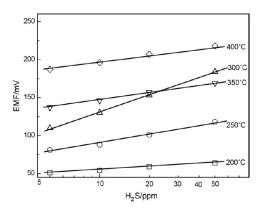


Fig. 1. Dependence of EMF of the sensor attached with Pr_6O_{11} -doped SnO_2 on the H_2S concentration at $200\text{-}400^{\circ}\text{C}$.

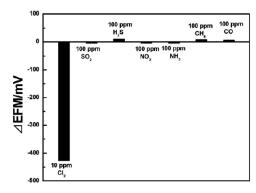


Fig. 2. Cross-EMF responses of the sensor using CaMg₃(SiO₃)₄-doped CdS to various gases at 200 °C.

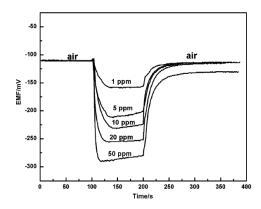


Fig. 3. Response transients of the sensor based on NASICON and V_2O_5 -doped TiO_2 sensing electrode to various concentrations of SO_2 at 300 °C.

Gas	Sensor structure Air, RE electrolyte SE, target gas	Sensitivity (mV/decade)	Gas conc. (ppm)	Operating temperature (°C)
H ₂ S	Air, Au NASICON Au, Pr ₆ O ₁₁ -SnO ₂ , H ₂ S(+air)	74	5-50	300
Cl ₂	Air, Au NASICON Au, Cd ₃ O ₂ SO ₄ , Cl ₂ (+air)	-392	1-10	200
SO ₂	Air, Au NASICON Au, V ₂ O ₅ -TiO ₂ , SO ₂ (+air)	-78	1-50	300
NH ₃	Air, Au NASICON Au, porous Cr₂O₃, NH₃ (+air)	-89	50-500	350
NO ₂	Air, Pt NASICON Au, NiO, NO ₂ (+air)	78	5-200	350
СО	Air, Pt NASICON Au, NiFe ₂ O ₄ , CO (+air)	-45	100-1000	350
СО	Air, Au NASICON Au, Y ₂ O ₃ CO (+air)	-45	5-50	400
C ₇ H ₈	Air, Au NASICON Au, Sm ₂ O ₃ C ₇ H ₈ (+air)	-75	5-50	350
NO	Air, Au NASICON Au, NiWO ₄ CO (+air)	70	5-500	350
NH ₃ / C ₇ H ₈	NH ₃ (+air) , Cr ₂ O ₃ , Au, NASICON Au, Air, Au NASICON Au, ZnO-TiO ₂ , C ₇ H ₈ (+air)	-91/-60	50-500 /5-50	350
Cl ₂	Air, NASICON Au NASICON Au, Cr ₂ O ₃ , Cl ₂ (+air)	-270	1-50	300

Table 1 Typical examples of mixed-potential type gas sensors utilizing NASICON and different oxide electrodes

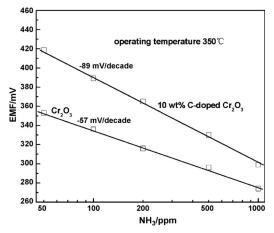


Fig. 4. Dependence of EMF on NH₃ concentration for the sensor attached with the undoped Cr_2O_3 and the 10 wt% C-doped Cr_2O_3 .

electrode. Fig. 5 showed the structure as well as the response transients to different concentrations of NH $_3$ and C $_7$ H $_8$ for the dual-function sensor using Cr $_2$ O $_3$ and ZnO-TiO $_2$ at 350°C. It can be seen that the electrode A showed higher response to NH $_3$, but the electrode B displayed a higher response to C $_7$ H $_8$. The combining of electrodes A and B can realize the simultaneous measurement to these two kinds of gases [14].

A buried structure sensing device was developed by using Cr_2O_3 electrode, which can effectively prevent the reaction of the target gas on reference electrode [15]. Fig.6 shows the dependence of ΔEMF on the Cl_2 concentration for different type of sensor (type A: conventional device, type B: simple buried device and type C: deep-buried device), the sensitivity (-slope) for

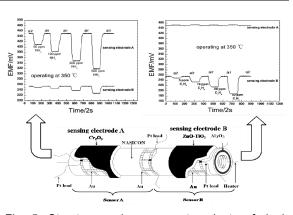


Fig. 5. Structure and response transients of dualfunction sensor using Cr_2O_3 and ZnO- TiO_2 for detection of NH_3 and C_7H_8 .

the type C was -270 mV/decade, which is much higher than those for type (A) (-119 mV/decade) and type (B) (-157 mV/decade). This suggested covering reference electrode NASICON in Type B and C can block the contact of RE with the Cl₂ and restrain electrochemical reaction in the reference electrode. The potential difference between the sensing and reference electrode as well as the sensitivity of the sensor has been obviously increased. The other way to enhance the sensitivity is to increase the effective area of the sensing electrode. For the sensor A and B, because the sensing electrode and reference electrode were located at both ends of the same NASICON layer, the area of the sensing electrode was reduced to about one half of the surface area of the first NASICON layer. However, for Type C, since the sensing electrode almost covers the all of the surface area of the second NASICON layer (Fig. 1 (C)), the area of the sensing electrode is greatly enlarged, and the sensitivity of the Type C is obviously enhanced.

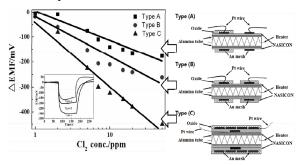


Fig. 6. The buried structure sensor using Cr_2O_3 for detection of Cl_2 .

4. Conclusions

The mixed potential type sensors utilizing NASICON and oxide electrodes have been developed and showed a potential for detecting the harmful and toxic gases in the atmosphere.

Acknowledgements

Support by NSFC (Nos. 61074172, 61134010, 61104203) and Program for Chang jiang Scholars and Innovative Research Team in University (No. IRT1017) and Jilin province science and technology development plan program (20106002) is gratefully acknowledged.

References

- [1] N. Barsan, M. Hübner, U. Weimar, Conduction mechanisms in SnO₂ based polycrystalline thick film gas sensors exposed to CO and H₂ in different oxygen backgrounds, Sensors and Actuators B 157, 510–517 (2011); doi:10.1016 /j.snb.2011.05.011.
- [2] T. Miyata, T. Minami, Chlorine gas sensors with high sensitivity using Mg-phthalocyanine thin films, Applied Surface Science, 244, 563-567 (2005); doi: 10.1016/j.apsusc.2004.10.120.
- [3] S. Zhuiykov, N. Miura, Development of zirconia-based potentiometric NO_x sensors for automotive and energy industries in the early 21st century: What are the prospects for sensors? Sensors and Actuators B 121, 639–651 (2007); doi: 10.1016/j.snb.2006.03.044.
- [4] M. Ono, K. Shimanoe, N. Miura, N. Yamazoe, Reaction analysis on sensing electrode of amperometric NO₂ sensor based on sodium ion conductor by using chronopotentiometry, *Sensors* and Actuators B, 77, 78-83 (2001); doi:10.1016/S0925-4005(01) 00676-1.
- [5] N. Miura, S. Yao, Y. Shimizu, N. Yamazoe, Highperformance solid-electrolyte carbon dioxide sensor with a binary carbonate electrode,

- Sensors and Actuators B, 9, 165-170 (1992); doi:10.1016/0167-2738 (94) 90375 1,
- [6] T. Kida, K. Shimanoe, N. Miura, N. Yamazoe, Stability of NASICON-based CO₂ sensor under humid conditions at low temperature , Sensors and Actuators B, 75, 179-187 (2001); doi:10.1016/S0925-4005(01) 00549-4,
- [7] B.-K. Min, S.-D. Choi, SO₂-sensing characteristics of Nasicon sensors with Na₂SO₄— BaSO₄ auxiliary electrolytes, Sensors and Actuators B, 93, 209-213 (2003); doi:10.1016/ S0925-4005(03)00210-7.
- [8] K. Obata, S. Matsushima, NASICON-based NO₂ device attached with metal oxide and nitrite compound for the low temperature operation, *Sensors and Actuators B*, 130269-276 (2008); doi:10.1016/j.snb.2007.07.142.
- [9] Y. Shimizu, N. Yamashita, Solid electrolyte CO₂ sensor using NASICON and perovskite-type oxide electrode, Sensors and Actuators B, 64, 102-106 (2000); doi:10.1016/ S0925-4005(99)00491-8.
- [10] X. Liang, Y. He, F. Liu, B. Wang, T. Zhong, B. Quan, G. Lu, Solid-state potentiometric H₂S sensor combining NASICON with Pr₆O₁₁-doped SnO₂ electrode, *Sensors and Actuators B*, 125, 544-549 (2007); doi:10.1016/j.snb.2007.02.050.
- [11] X. Liang, F. Liu, T. Zhong, B. Wang, B. Quan, G. Lu, Chlorine sensor combining NASICON with CaMg₃(SiO₃)₄-doped CdS electrode, *Solid State Ionics*, 179, 1636-1640 (2008); doi.org/10.1016/j.ssi.2008. 01.004.
- [12] X. Liang, T. Zhong, B. Quan, B. Wang, H.Guan, Solid-state potentiometric SO_2 sensor combining NASICON with V_2O_5 -doped TiO_2 electrode, Sensors and Actuators B, 134, 25-30 (2008); doi:10.1016/j.snb.2008.04.003.
- [13] Xishuang Liang, Tiegang Zhong, Hesong Guan, Fengmin Liu, Geyu Lu, Baofu Quan, Ammonia sensor based on NASICON and Cr₂O₃ electrode, Sensors and Actuators B 136, 479-483 (2009); doi:10.1016/j.snb.2008.11.028,
- [14] X. Liang, G. Lu, T. Zhong, F. Liu, B. Quan, New type of ammonia/toluene sensor combining NASICON with a couple of oxide electrodes, Sensors and Actuators B, 150, 355-359 (2010); doi:10.1016/j.snb.2010.06.061.
- [15] Zhang H., Liang X.; Li J., Lu G., NASICON-Based Potentiometric Cl_2 Sensor Combining NASICON with Cr_2O_3 Sensing Electrode, TRANSDUCERS 2011, 174 177(2011); doi:10.1109/TRANSDUCERS. 2011.5969253.